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TEXAS INSTRUMENTS

SN74LVC1G11

SCES487H – SEPTEMBER 2003 – REVISED NOVEMBER 2016

SN74LVC1G11 Single 3-Input Positive-AND Gate

1 Features

- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 1000-V Charged-Device Model (C101)
- Available in the Texas Instruments NanoFree™ Package
- Supports 5-V V_{CC} Operation
- Inputs Accept Voltages to 5.5 V
- Maximum t_{pd} of 4.1 ns at 3.3 V
- Low Power Consumption, 10-μA Maximum I_{CC}
- ±24-mA Output Drive at 3.3 V
- I_{off} Supports Partial-Power-Down Mode Operation

2 Applications

- AV Receivers
- DLP Front Projection System
- Digital Picture Frames
- Digital Radio
- Digital Still Cameras
- Digital Video Cameras (DVC)
- Embedded PCs
- E-Books
- Ethernet Switchs
- GPS: Personal Navigation Devices
- Handset: Smartphones
- High-Speed Data Acquisition and Generation
- Military: Radar and Sonar
- Mobile Internet Devices
- Notebook PC and Netbooks
- Network-Attached Storage (NAS)
- Power Line Communication Modems
- Server PSU
- STB, DVR, and Streaming Media
- Speakers: USB
- Tablets: Enterprise
- Video Broadcasting and Infrastructure: Scalable Platform and IP-Based Multi-Format Transcoders
- Wireless Headsets, Keyboards, and Mice

3 Description

The SN74LVC1G11 performs the Boolean function $Y = A \cdot B \cdot C$ or $Y = \overline{A} + \overline{B} + \overline{C}$ in positive logic.

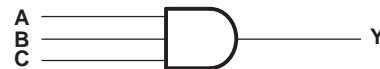NanoFree package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

Device Information[1]

PART NUMBER	PACKAGE	BODY SIZE (NOM)
SN74LVC1G11DBV	SOT-23 (6)	2.90 mm × 1.60 mm
SN74LVC1G11DCK	SC70 (6)	2.00 mm × 1.25 mm
SN74LVC1G11DRY	SON (6)	1.45 mm × 1.00 mm
SN74LVC1G11DSF	SON (6)	1.00 mm × 1.00 mm
SN74LVC1G11YZP	DSBGA (6)	1.41 mm × 0.91 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Logic Diagram (Positive Logic)

Table of Contents

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision G (December 2015) to Revision H   **Page**

Changes from Revision F (December2013) to Revision G   **Page**

Changes from Revision E (December 2011) to Revision F   **Page**

Changes from Revision D (January 2007) to Revision E   **Page**

Product Folder Links: *SN74LVC1G11*

5 Pin Configuration and Functions

DBV Package
6-Pin SOT-23
Top View

Not to scale

DCK Package
6-Pin SC70
Top View

Not to scale

YZP Package
6-Pin DSBGA
Bottom View

Not to scale

DRY Package
6-Pin SON
Top View

Not to scale

DSF Package
6-Pin SON
Top View

Not to scale
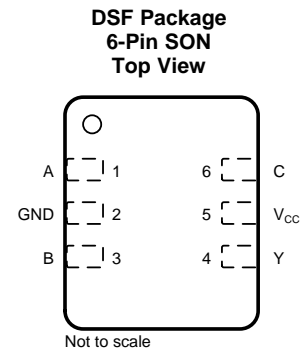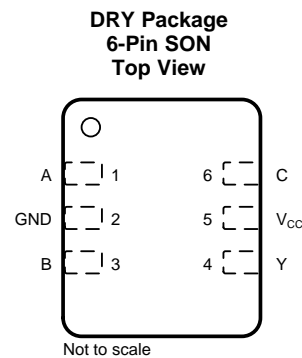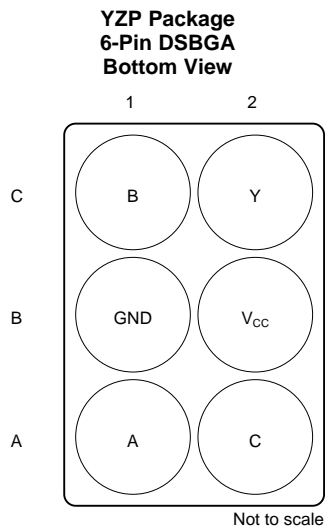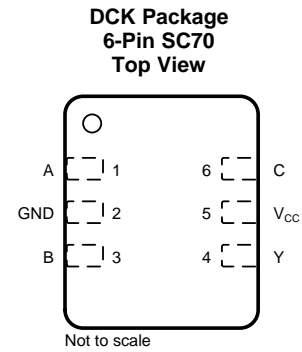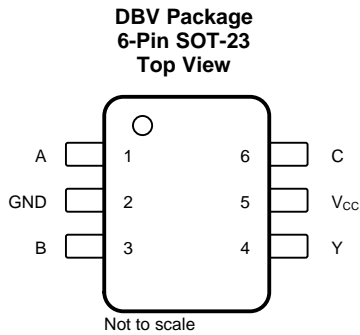
See mechanical drawings for dimensions.

Pin Functions

PIN			I/O	DESCRIPTION
NAME	SOT-23, SC70, SON, SON	DSBGA		
A	1	A1	I	A Input
B	3	C1	I	B Input
C	6	A2	I	C Input
GND	2	B1	—	Ground
V_{CC}	5	B2	—	Power Supply
Y	4	C2	O	Y Output

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)[1]

			MIN	MAX	UNIT
V_{CC}	Supply voltage		–0.5	6.5	V
V_I	Input voltage[2]		–0.5	6.5	V
V_O	Voltage applied to any output in the high-impedance or power-off state[2]		–0.5	6.5	V
V_O	Voltage applied to any output in the high or low state[2][3]		–0.5	V_{CC} + 0.5	V
I_{IK}	Input clamp current	$V_I < 0$		–50	mA
I_{OK}	Output clamp current	$V_O < 0$		–50	mA
I_O	Continuous output current			±50	mA
	Continuous current through V_{CC} or GND			±100	mA
T_J	Junction temperature			150	°C
T_{stg}	Storage temperature		–65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.
(3) The value of V_{CC} is provided in the *Recommended Operating Conditions* table.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001[1]	2000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101[2]	1000	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

See note[1].

			MIN	MAX	UNIT
V_{CC}	Supply voltage	Operating	1.65	5.5	V
		Data retention only	1.5		
V_{IH}	High-level input voltage	V_{CC} = 1.65 V to 1.95 V	$0.65 \times V_{CC}$		V
		V_{CC} = 2.3 V to 2.7 V	1.7		
		V_{CC} = 3 V to 3.6 V	2		
		V_{CC} = 4.5 V to 5.5 V	$0.7 \times V_{CC}$		
V_{IL}	Low-level input voltage	V_{CC} = 1.65 V to 1.95 V		$0.35 \times V_{CC}$	V
		V_{CC} = 2.3 V to 2.7 V		0.7	
		V_{CC} = 3 V to 3.6 V		0.8	
		V_{CC} = 4.5 V to 5.5 V		$0.3 \times V_{CC}$	
V_I	Input voltage		0	5.5	V
V_O	Output voltage		0	V_{CC}	V
I_{OH}	High-level output current	V_{CC} = 1.65 V		–4	mA
		V_{CC} = 2.3 V		–8	
		V_{CC} = 3 V		–16	
				–24	
		V_{CC} = 4.5 V		–32	

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. See *Implications of Slow or Floating CMOS Inputs*, SCBA004.

Product Folder Links: *SN74LVC1G11*

Recommended Operating Conditions (continued)

See note[1].

			MIN	MAX	UNIT
I_{OL}	Low-level output current	V_{CC} = 1.65 V		4	mA
		V_{CC} = 2.3 V		8	
		V_{CC} = 3 V		16	
				24	
		V_{CC} = 4.5 V		32	
$\Delta t/\Delta v$	Input transition rise or fall rate	V_{CC} = 1.8 V ± 0.15 V, 2.5 V ± 0.2 V		20	ns/V
		V_{CC} = 3.3 V ± 0.3 V		10	
		V_{CC} = 5 V ± 0.5 V		10	
T_A	Operating free-air temperature	BGA package	−40	85	°C
		All other packages	−40	125	

6.4 Thermal Information

		SN74LVC1G11					
THERMAL METRIC[1]		DBV (SOT-23)	DCK (SC70)	DRY (SON)	YZP (DSBGA)	DSF (SON)	UNIT
		6 PINS	6 PINS	6 PINS	6 PINS	6 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	195.9	260.1	424.6	105.8	413.7	°C/W
$R_{\theta JCtop}$	Junction-to-case (top) thermal resistance	177.4	98.1	309	1.6	226.6	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	51.7	63.1	292	10.8	317	°C/W
ψ_{JT}	Junction-to-top characterization parameter	61.3	2.2	135.4	3.1	37.4	°C/W
ψ_{JB}	Junction-to-board characterization parameter	51.3	62.4	292	10.8	317	°C/W
$R_{\theta JCbot}$	Junction-to-case (bottom) thermal resistance	—	—	—	—	—	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

6.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V_{CC}	MIN	TYP	MAX	UNIT
V_{OH}		I_{OH} = −100 µA	1.65 V to 5.5 V	V_{CC} − 0.1			V
		I_{OH} = −4 mA	1.65 V	1.2			
		I_{OH} = −8 mA	2.3 V	1.9			
		I_{OH} = −16 mA	3 V	2.4			
		I_{OH} = −24 mA		2.3			
		I_{OH} = −32 mA	4.5 V	3.8			
V_{OL}		I_{OL} = 100 µA	1.65 V to 5.5 V			0.1	V
		I_{OL} = 4 mA	1.65 V			0.45	
		I_{OL} = 8 mA	2.3 V			0.3	
		I_{OL} = 16 mA	3 V			0.4	
		I_{OL} = 24 mA				0.55	
		I_{OL} = 32 mA	4.5 V			0.55	
I_I	All inputs	V_I = 5.5 V or GND	0 to 5.5 V			±5	µA
I_{off}		V_I or V_O = 5.5 V	0			±10	µA
I_{CC}		V_I = 5.5 V or GND, I_O = 0	1.65 V to 5.5 V			10	µA
ΔI_{CC}		One input at V_{CC} − 0.6 V, Other inputs at V_{CC} or GND	3 V to 5.5 V			500	µA
C_i		V_I = V_{CC} or GND	3.3 V		3.5		pF

6.6 Switching Characteristics, C_L = 15 pF, T_A = –40°C to +85°C

over recommended operating free-air temperature range, C_L = 15 pF (unless otherwise noted) (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC}	MIN	MAX	UNIT
t_{pd}	A, B, or C	Y	V_{CC} = 1.8 V ± 0.15 V	2.6	15.2	ns
			V_{CC} = 2.5 V ± 0.2 V	1.6	5.6	
			V_{CC} = 3.3 V ± 0.3 V	1.2	4.1	
			V_{CC} = 5 V ± 0.5 V	1	3.1	

6.7 Switching Characteristics, C_L = 30 pF or 50 pF, T_A = –40°C to +85°C

over recommended operating free-air temperature range, C_L = 30 pF or 50 pF (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC}	MIN	MAX	UNIT
t_{pd}	A, B, or C	Y	V_{CC} = 1.8 V ± 0.15 V	2.9	17.2	ns
			V_{CC} = 2.5 V ± 0.2 V	1.4	6.2	
			V_{CC} = 3.3 V ± 0.3 V	1.3	4.9	
			V_{CC} = 5 V ± 0.5 V	1	3.5	

6.8 Switching Characteristics, C_L = 30 pF or 50 pF, T_A = –40°C to +125°C

over recommended operating free-air temperature range, C_L = 30 pF or 50 pF (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC}	MIN	MAX	UNIT
t_{pd}	A, B, or C	Y	V_{CC} = 1.8 V ± 0.15 V	2.9	20	ns
			V_{CC} = 2.5 V ± 0.2 V	1.4	7.8	
			V_{CC} = 3.3 V ± 0.3 V	1.3	6.2	
			V_{CC} = 5 V ± 0.5 V	1	4.6	

6.9 Operating Characteristics

T_A = 25°C

PARAMETER	TEST CONDITIONS	V_{CC}	TYP	UNIT
C_{pd} Power dissipation capacitance	f = 10 MHz	V_{CC} = 1.8 V	18	pF
		V_{CC} = 2.5 V	19	
		V_{CC} = 3.3 V	20	
		V_{CC} = 5 V	23	

Product Folder Links: *SN74LVC1G11*

6.10 Typical Characteristics
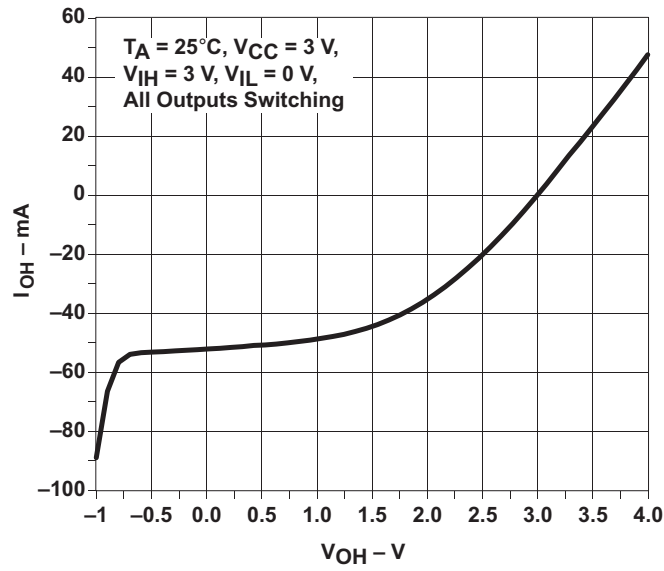
**Figure 1. Output Current Drive
vs HIGH-level Output Voltage**

Product Folder Links: *SN74LVC1G11*

7 Parameter Measurement Information
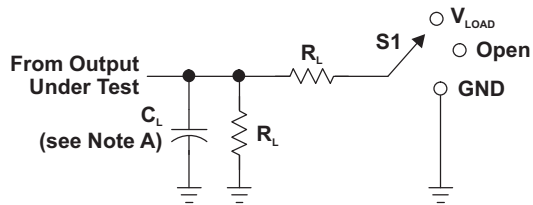
LOAD CIRCUIT

TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	V_{LOAD}
t_{PHZ}/t_{PZH}	GND

V_{CC}	INPUTS		V_M	V_{LOAD}	C_L	R_L	V_Δ
	V_I	t_r/t_f					
1.8 V ± 0.15 V	V_{CC}	≤2 ns	$V_{CC}/2$	$2 \times V_{CC}$	15 pF	1 MΩ	0.15 V
2.5 V ± 0.2 V	V_{CC}	≤2 ns	$V_{CC}/2$	$2 \times V_{CC}$	15 pF	1 MΩ	0.15 V
3.3 V ± 0.3 V	3 V	≤2.5 ns	1.5 V	6 V	15 pF	1 MΩ	0.3 V
5 V ± 0.5 V	V_{CC}	≤2.5 ns	$V_{CC}/2$	$2 \times V_{CC}$	15 pF	1 MΩ	0.3 V

**VOLTAGE WAVEFORMS
PULSE DURATION**

**VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES**

**VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS**

**VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING**

NOTES: A. C_L includes probe and jig capacitance.
  B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control.
      Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω.
  D. The outputs are measured one at a time, with one transition per measurement.
  E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
  F. t_{PZL} and t_{PZH} are the same as t_{en}.
  G. t_{PLH} and t_{PHL} are the same as t_{pd}.
  H. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms

Product Folder Links: *SN74LVC1G11*

Parameter Measurement Information (continued)

LOAD CIRCUIT

From Output Under Test — R_L — S1 — V_{LOAD} / Open / GND

C_L (see Note A), R_L

TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	V_{LOAD}
t_{PHZ}/t_{PZH}	GND

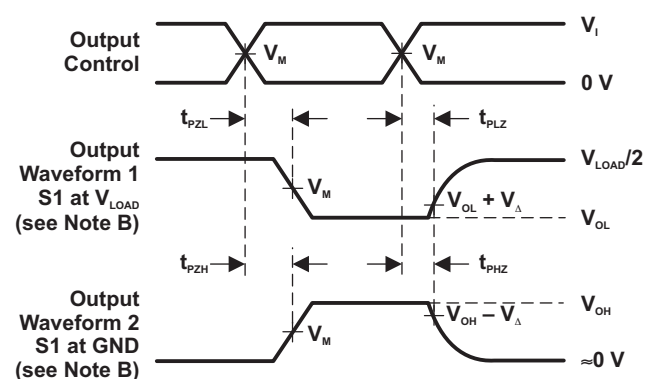| V_{CC}	INPUTS		V_M	V_{LOAD}	C_L	R_L	V_Δ
	V_I	t_r/t_f					
1.8 V ± 0.15 V	V_{CC}	≤2 ns	$V_{CC}/2$	2 × V_{CC}	30 pF	1 kΩ	0.15 V
2.5 V ± 0.2 V	V_{CC}	≤2 ns	$V_{CC}/2$	2 × V_{CC}	30 pF	500 Ω	0.15 V
3.3 V ± 0.3 V	3 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
5 V ± 0.5 V	V_{CC}	≤2.5 ns	$V_{CC}/2$	2 × V_{CC}	50 pF	500 Ω	0.3 V

VOLTAGE WAVEFORMS
PULSE DURATION

VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES

VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
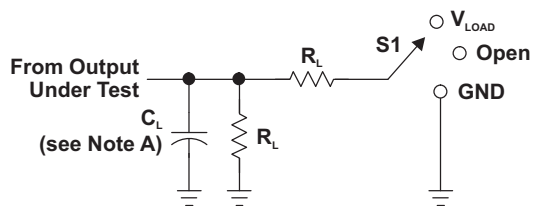**INVERTING AND NONINVERTING OUTPUTS**

VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING

NOTES: A. C_L includes probe and jig capacitance.
   B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control.
      Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
   C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω.
   D. The outputs are measured one at a time, with one transition per measurement.
   E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
   F. t_{PZL} and t_{PZH} are the same as t_{en}.
   G. t_{PLH} and t_{PHL} are the same as t_{pd}.
   H. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms

Product Folder Links: SN74LVC1G11

8 Detailed Description

8.1 Overview

This 3-input AND gate is designed for 1.65-V to 5.5-V V_{CC} operation.

The SN74LVC1G11 device features a three-input AND gate. The output state is determined by eight patterns of 3-bit input. All inputs can be connected to V_{CC} or GND.

This device is fully-specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

8.2 Functional Block Diagram

Figure 4. Logic Diagram (Positive Logic)

8.3 Feature Description

The SN74LVC1G11 device has a wide operating V_{CC} range of 1.65 V to 5.5 V, which allows use in a broad range of systems. The 5.5-V I/Os allow down translation and also allow voltages at the inputs when $V_{CC} = 0$ V.

8.4 Device Functional Modes

Table 1 lists the functional modes of SN74LVC1G11.

Table 1. Function Table

INPUTS			OUTPUT
A	B	C	Y
H	H	H	H
L	X	X	L
X	L	X	L
X	X	L	L

Product Folder Links: *SN74LVC1G11*

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Validate and test the design implementation to confirm system functionality.

9.1 Application Information

The SN74LVC1G11 device offers logical AND configuration for many design applications. This example describes basic power sequencing using the AND gate configuration. Power sequencing is often used in applications that require a processor or other delicate device with specific voltage timing requirements in order to protect the device from malfunctioning. In the application below, the power-good signals from the supplies tell the MCU to continue an operation.
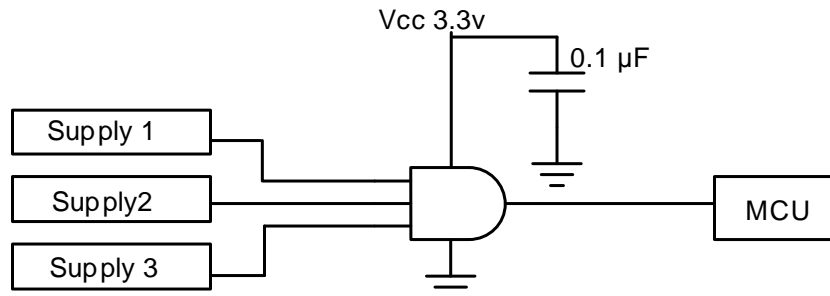
9.2 Typical Application

Figure 5. Typical Application Diagram

9.2.1 Design Requirements

- Recommended input conditions:
    - For rise time and fall time specifications, see Δt/Δv in the *Recommended Operating Conditions* table.
    - For specified high and low levels, see V_{IH} and V_{IL} in the *Recommended Operating Conditions* table.
    - Inputs and outputs are overvoltage tolerant and can therefore go as high as 5.5 V at any valid V_{CC}.
- Recommended output conditions:
    - Load currents must not exceed ±50 mA.
- Frequency selection criterion:
    - Figure 6 illustrates the effects of frequency on output current.
    - Added trace resistance and capacitance can reduce maximum frequency capability. Follow the layout practices listed in the *Layout* section.

Product Folder Links: *SN74LVC1G11*

Typical Application (continued)

9.2.2 Detailed Design Procedure

The SN74LVC1G11 device uses CMOS technology and has balanced output drive. Avoid bus contentions that can drive currents that can exceed maximum limits.

The SN74LVC1G11 allows for performing the logical AND function with digital signals. Maintain input signals as close as possible to either 0 V or V_{CC} for optimal operation.

9.2.3 Application Curve

$$V_{CC} = 5 \text{ V}$$
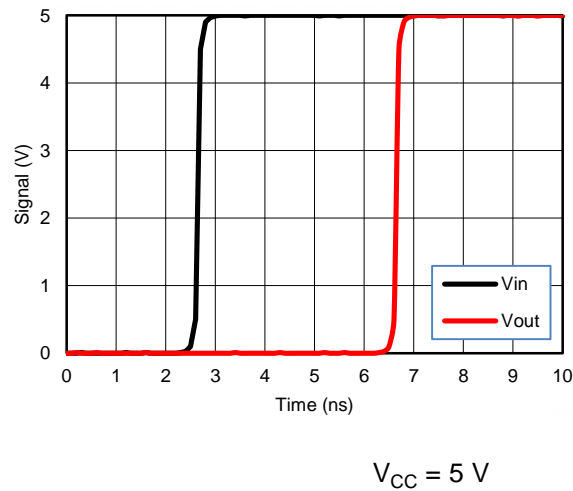
Figure 6. Simulated Input-to-Output Voltage Response Showing Propagation Delay

10 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating listed in the *Recommended Operating Conditions* table.

To prevent power disturbance, ensure good bypass capacitance for each V_{CC} terminal. For devices with a single-supply, a 0.1-µF bypass capacitor is recommended. If multiple pins are labeled V_{CC}, then a 0.01-µF or 0.022-µF capacitor is recommended for each V_{CC} because the V_{CC} pins are tied together internally. For devices with dual supply pins operating at different voltages, for example V_{CC} and V_{DD}, a 0.1-µF bypass capacitor is recommended for each supply pin. To reject different frequencies of noise, use multiple bypass capacitors in parallel. Capacitors with values of 0.1 µF and 1 µF are commonly used in parallel. Place the bypass capacitor as close to the power terminal as possible for best results.

Product Folder Links: *SN74LVC1G11*

11 Layout

11.1 Layout Guidelines

When using multiple-bit logic devices, inputs must never float.

In many cases, functions (or parts of functions) of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or when only 3 of the 4 buffer gates are used. Such input pins must not be left unconnected, because the undefined voltages at the outside connections result in undefined operational states. Figure 7 specifies the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally they are tied to GND or V_{CC}, whichever makes more sense or is more convenient. It is generally acceptable to float outputs, unless the part is a transceiver. If the transceiver has an output enable pin, it disables the output section of the part when asserted, which does not disable the input section of the I/Os. Therefore, the I/Os cannot float when disabled.
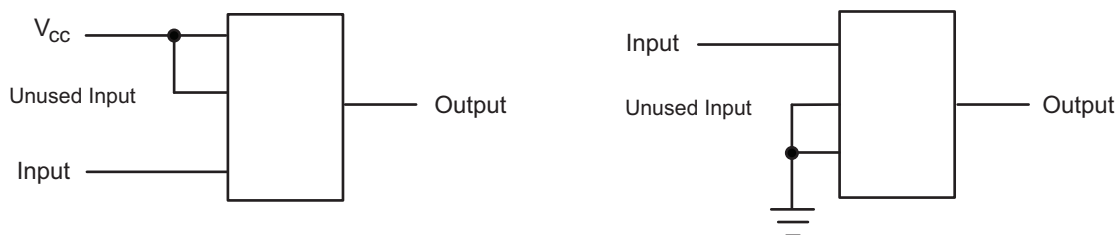
11.2 Layout Example

Figure 7. Layout Diagrams

Product Folder Links: SN74LVC1G11

12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

For related documentation see the following:
- *Implications of Slow or Floating CMOS Inputs*, SCBA004
- *Selecting the Right Texas Instruments Signal Switch*, SZZA030

12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.4 Trademarks

NanoFree, E2E are trademarks of Texas Instruments.
All other trademarks are the property of their respective owners.

12.5 Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser based versions of this data sheet, refer to the left hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVC1G11DBVR	ACTIVE	SOT-23	DBV	6	3000	RoHS & Green	NIPDAU | SN	Level-1-260C-UNLIM	-40 to 125	(C115, C11F, C11K, C11R)	Samples
SN74LVC1G11DBVRE4	ACTIVE	SOT-23	DBV	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C11F	Samples
SN74LVC1G11DBVRG4	ACTIVE	SOT-23	DBV	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C11F	Samples
SN74LVC1G11DCKR	ACTIVE	SC70	DCK	6	3000	RoHS & Green	NIPDAU | SN	Level-1-260C-UNLIM	-40 to 125	(C35, C3F, C3J, C3 K, C3R)	Samples
SN74LVC1G11DCKRE4	ACTIVE	SC70	DCK	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C35	Samples
SN74LVC1G11DCKRG4	ACTIVE	SC70	DCK	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C35	Samples
SN74LVC1G11DRYR	ACTIVE	SON	DRY	6	5000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C3	Samples
SN74LVC1G11DSFR	ACTIVE	SON	DSF	6	5000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C3	Samples
SN74LVC1G11YZPR	ACTIVE	DSBGA	YZP	6	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	C3N	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN74LVC1G11 :

● Automotive: SN74LVC1G11-Q1

● Enhanced Product: SN74LVC1G11-EP

NOTE: Qualified Version Definitions:

  ● Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

  ● Enhanced Product - Supports Defense, Aerospace and Medical Applications

TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC1G11DBVR	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
SN74LVC1G11DBVRG4	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G11DCKR	SC70	DCK	6	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
SN74LVC1G11DCKRG4	SC70	DCK	6	3000	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74LVC1G11DRYR	SON	DRY	6	5000	180.0	9.5	1.15	1.6	0.75	4.0	8.0	Q1
SN74LVC1G11DSFR	SON	DSF	6	5000	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q2

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC1G11DBVR	SOT-23	DBV	6	3000	210.0	185.0	35.0
SN74LVC1G11DBVRG4	SOT-23	DBV	6	3000	180.0	180.0	18.0
SN74LVC1G11DCKR	SC70	DCK	6	3000	210.0	185.0	35.0
SN74LVC1G11DCKRG4	SC70	DCK	6	3000	180.0	180.0	18.0
SN74LVC1G11DRYR	SON	DRY	6	5000	184.0	184.0	19.0
SN74LVC1G11DSFR	SON	DSF	6	5000	184.0	184.0	19.0

PIN 1
INDEX AREA

3.0
2.6

1.75
1.45

B

A

2X 0.95

1.9

3.05
2.75

6X 0.50
0.25

⊕ 0.2Ⓜ C A B

C

◯ 0.1 C

(1.1)

0.15
0.00 TYP

1.45 MAX

0.25

GAGE PLANE

0.22
0.08 TYP

8°
0° TYP

0.6
0.3 TYP

SEATING PLANE

ALTERNATIVE PACKAGE SINGULATION VIEW

4214840/E   02/2024
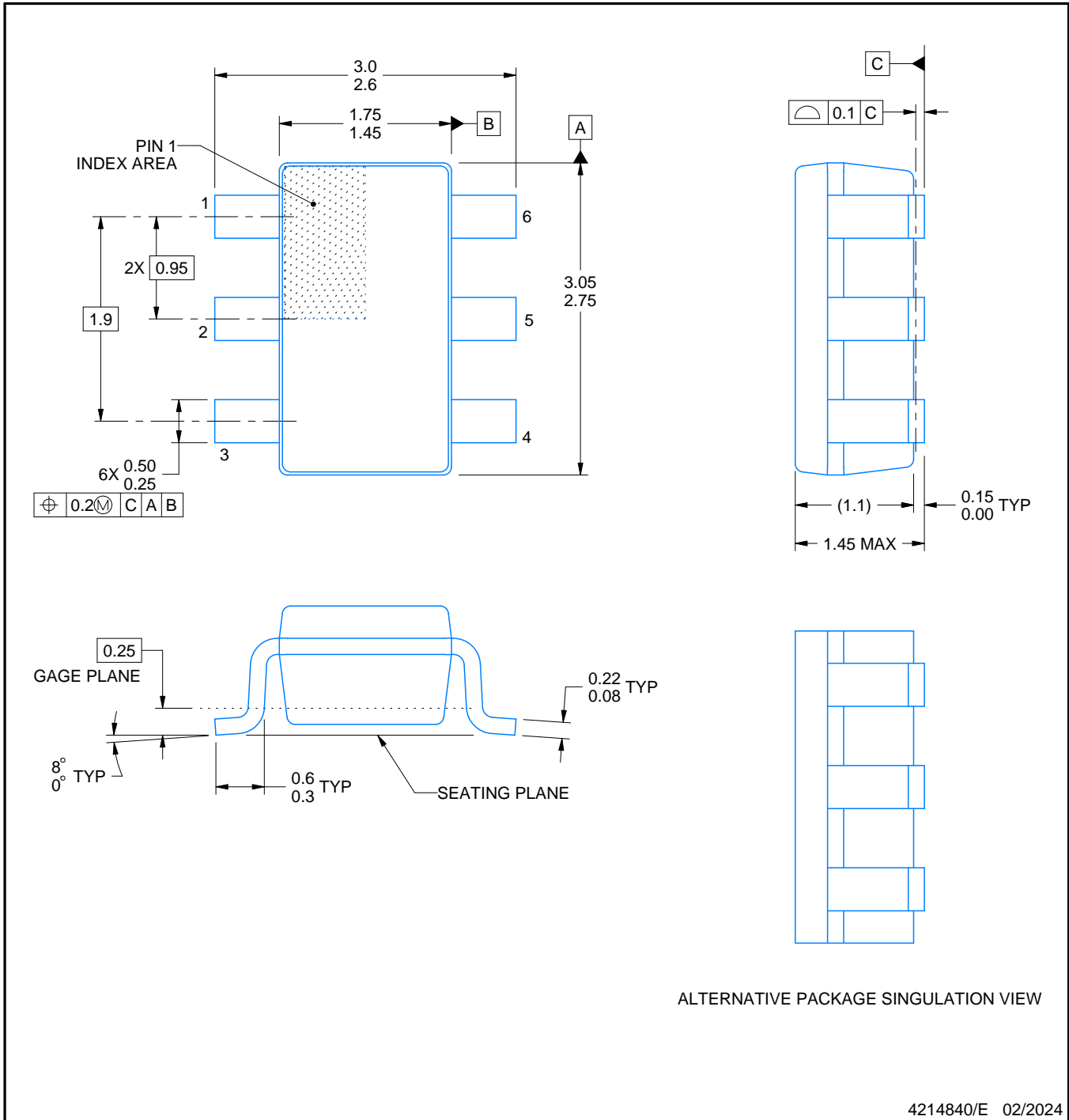
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.
4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
5. Refernce JEDEC MO-178.

6X (1.1)

PKG

1

6X (0.6)

6

2

SYMM

5

2X (0.95)

3

4

(R0.05) TYP

(2.6)
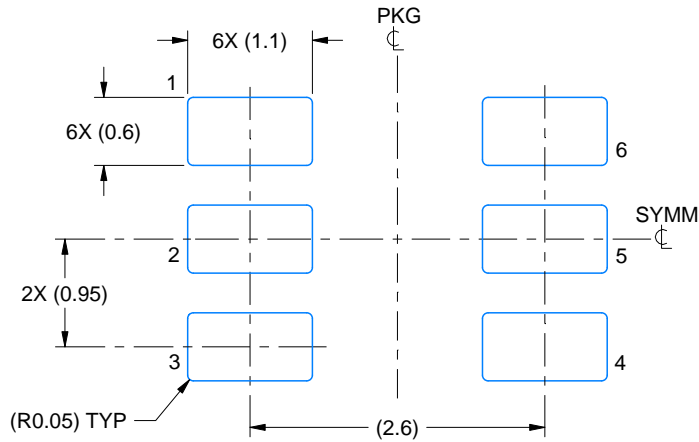
LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X

SOLDER MASK
OPENING

METAL

EXPOSED METAL

0.07 MAX
ARROUND

NON SOLDER MASK
DEFINED
(PREFERRED)

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

EXPOSED METAL

0.07 MIN
ARROUND

SOLDER MASK
DEFINED
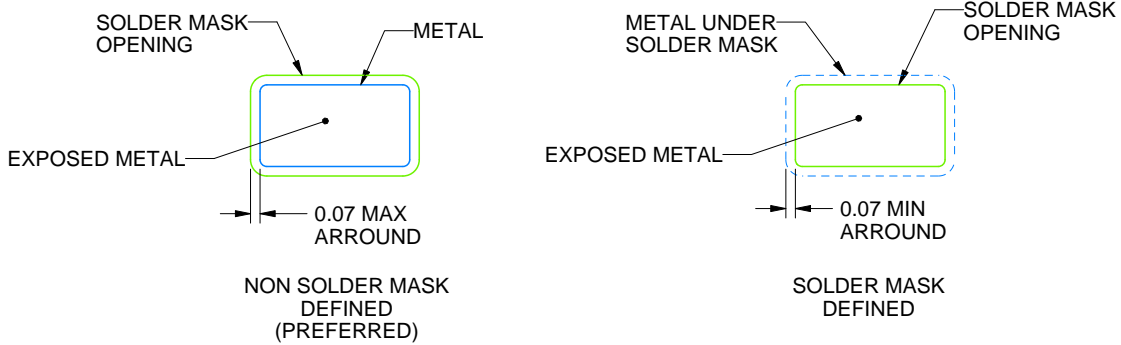
SOLDER MASK DETAILS

4214840/E   02/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

PKG

6X (1.1)

1

6X (0.6)

6

2

SYMM

5

2X(0.95)

3

4

(R0.05) TYP

(2.6)
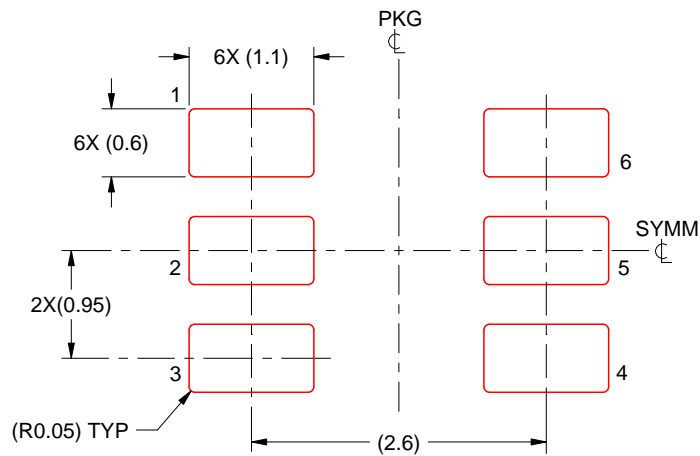
SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214840/E   02/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

BALL A1 CORNER

B ◄── E ──► A

D

0.5 MAX

0.19
0.15

BALL TYP

C

SEATING PLANE

⌒ | 0.05 | C

0.5 TYP

C

SYMM
₵
B

A

1 TYP

0.5 TYP

1   2

SYMM
₵

6X ⌀ 0.25
       0.21

⊕ | 0.015 Ⓢ | C | A Ⓢ | B Ⓢ |

D: Max = 1.418 mm, Min =1.358 mm

E: Max = 0.918 mm, Min =0.858 mm
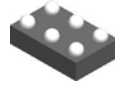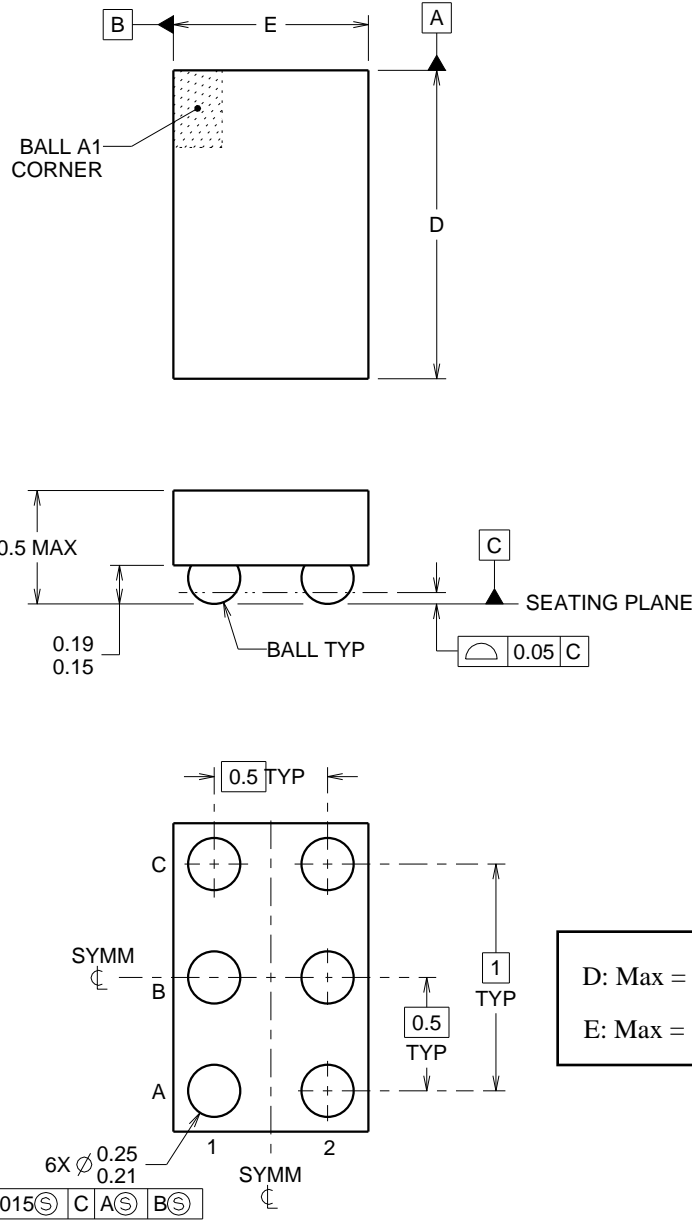
4219524/A   06/2014

NOTES:

NanoFree Is a trademark of Texas Instruments.
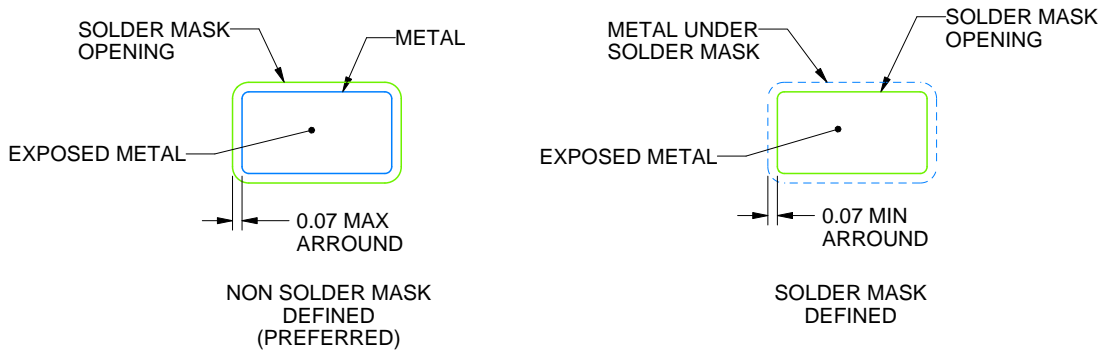
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing
   per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. NanoFree™ package configuration.

6X ($\emptyset$ 0.225)

(0.5) TYP

(0.5) TYP

1   2

A

B   SYMM $\mathrm{C_L}$

C

SYMM $\mathrm{C_L}$

LAND PATTERN EXAMPLE
SCALE:40X

($\emptyset$ 0.225)
METAL

0.05 MAX

SOLDER MASK
OPENING

**NON-SOLDER MASK
DEFINED
(PREFERRED)**

0.05 MIN

METAL
UNDER
MASK

($\emptyset$ 0.225)
SOLDER MASK
OPENING

**SOLDER MASK
DEFINED**
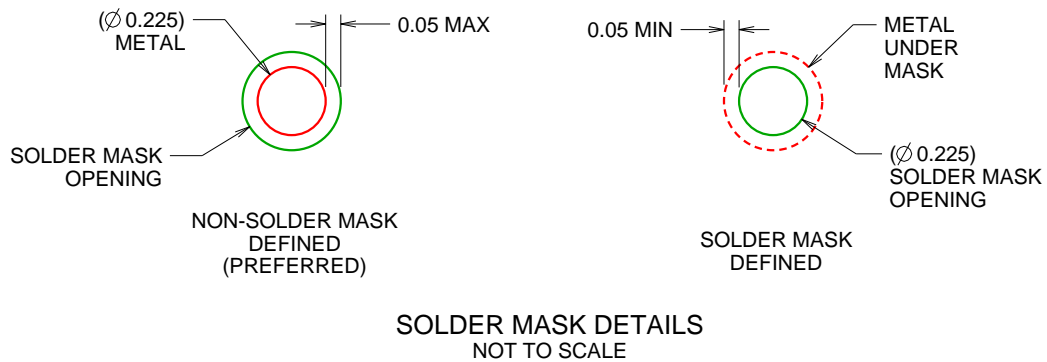
SOLDER MASK DETAILS
NOT TO SCALE

4219524/A   06/2014

NOTES: (continued)

4. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints.
   For more information, see Texas Instruments literature number SBVA017 (www.ti.com/lit/sbva017).

(0.5) TYP

6X (□ 0.25)

(R0.05) TYP

1

2

A

(0.5)
TYP

B

SYMM
₵

METAL
TYP

C

SYMM
₵
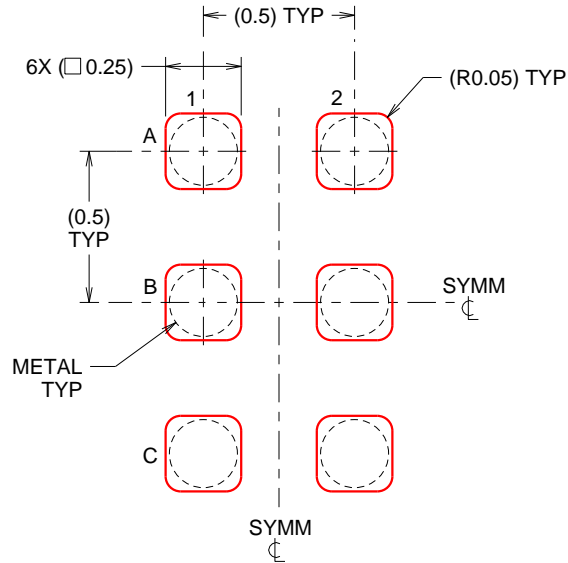
SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE:40X

4219524/A   06/2014

NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.
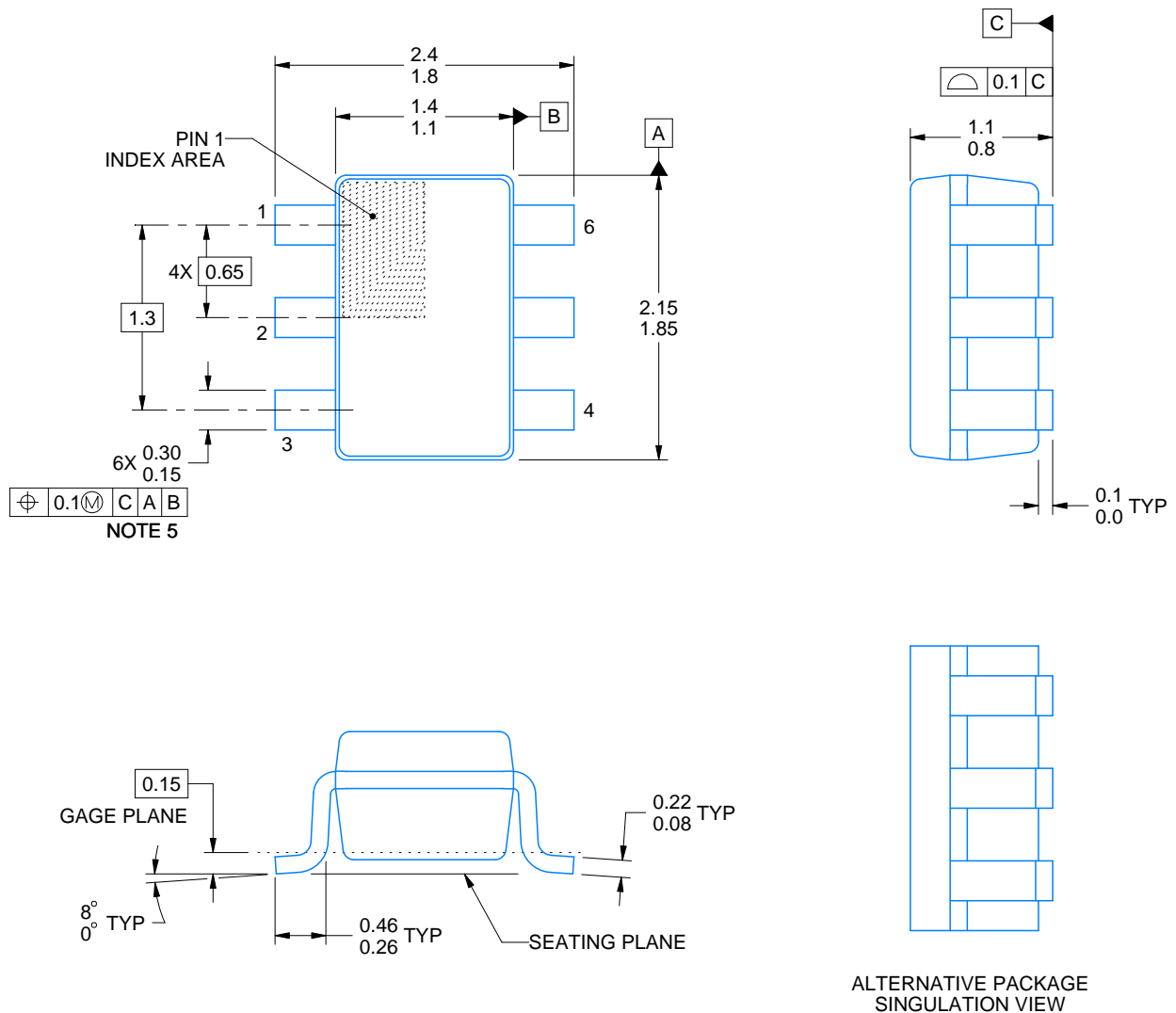
4214835/B   04/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
4. Falls within JEDEC MO-203 variation AB.

6X (0.9)

PKG

1

6X (0.4)

6

2

SYMM

4X (0.65)

3

(R0.05) TYP

4

(2.2)
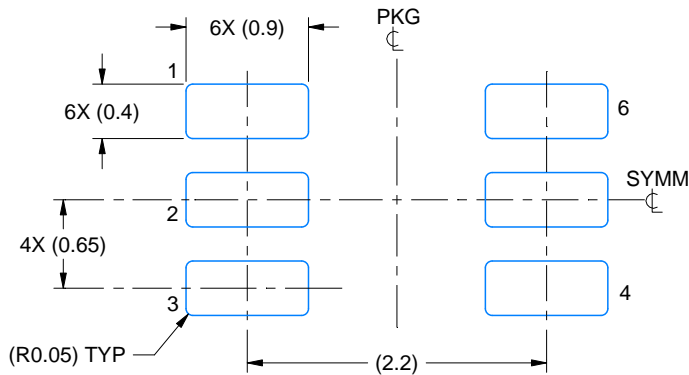
LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:18X

SOLDER MASK
OPENING

METAL

EXPOSED METAL

0.07 MAX
ARROUND

NON SOLDER MASK
DEFINED
(PREFERRED)

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

EXPOSED METAL

0.07 MIN
ARROUND

SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4214835/B 04/2024

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

DCK0006A

PKG

6X (0.9)

1

6X (0.4)

6

2

SYMM

4X(0.65)

3

4

(R0.05) TYP

(2.2)

SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:18X

4214835/B 04/2024

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate
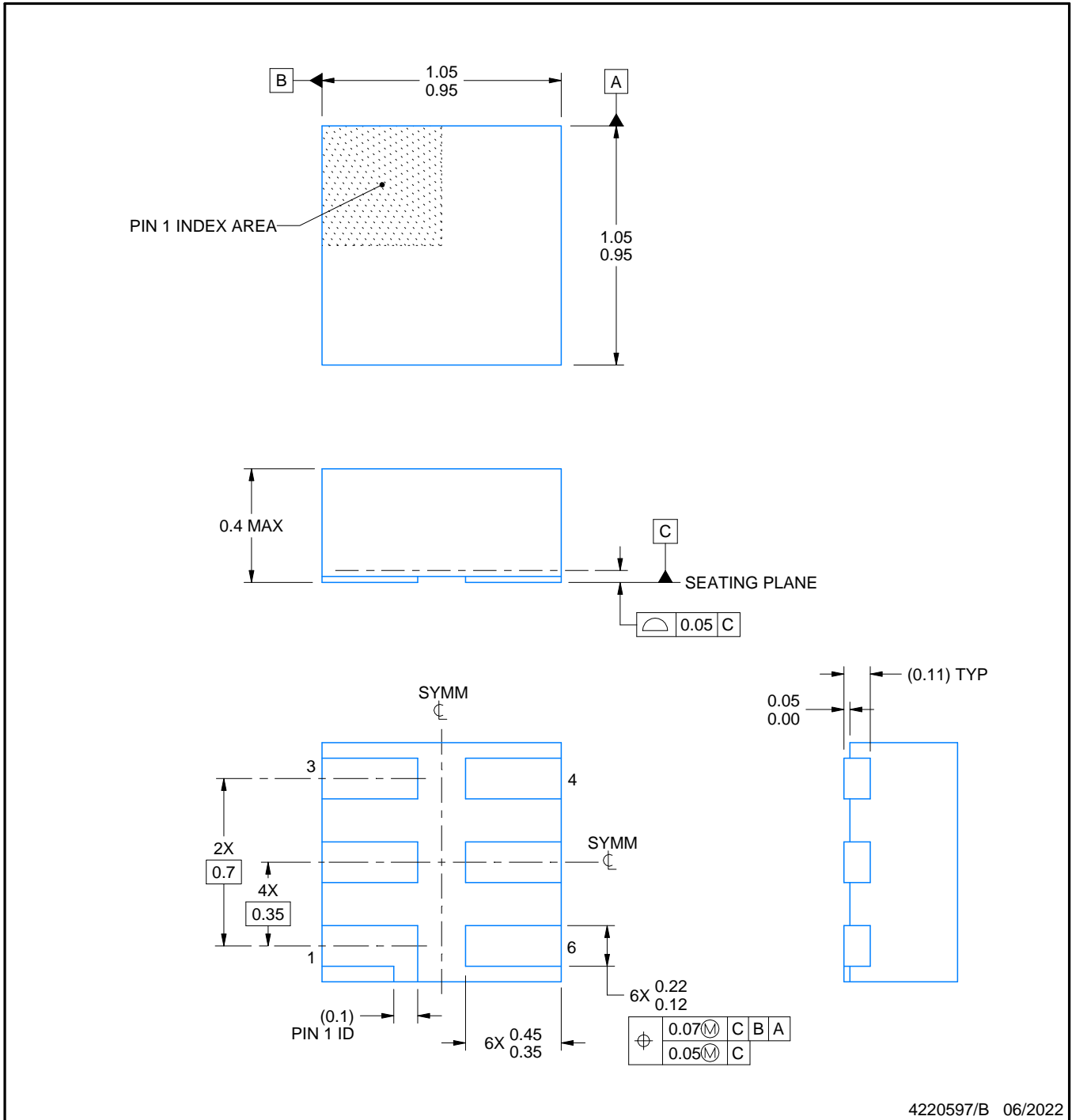   design recommendations.
8. Board assembly site may have different recommendations for stencil design.

Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

TEXAS
INSTRUMENTS

B | 1.05 / 0.95 | A

PIN 1 INDEX AREA

1.5 / 1.4

0.6 MAX

0.05 / 0.00

C

SEATING PLANE

⌒ 0.08 C

3X 0.6

SYMM ₵

(0.05) TYP

3

4X 0.5

2X 1

SYMM ₵

(0.127) TYP

4

0.4 / 0.3

1

6

PIN 1 ID (OPTIONAL)

6X 0.25 / 0.15

⊕ 0.1 Ⓜ C A B
  0.05 Ⓜ C

5X 0.35 / 0.25
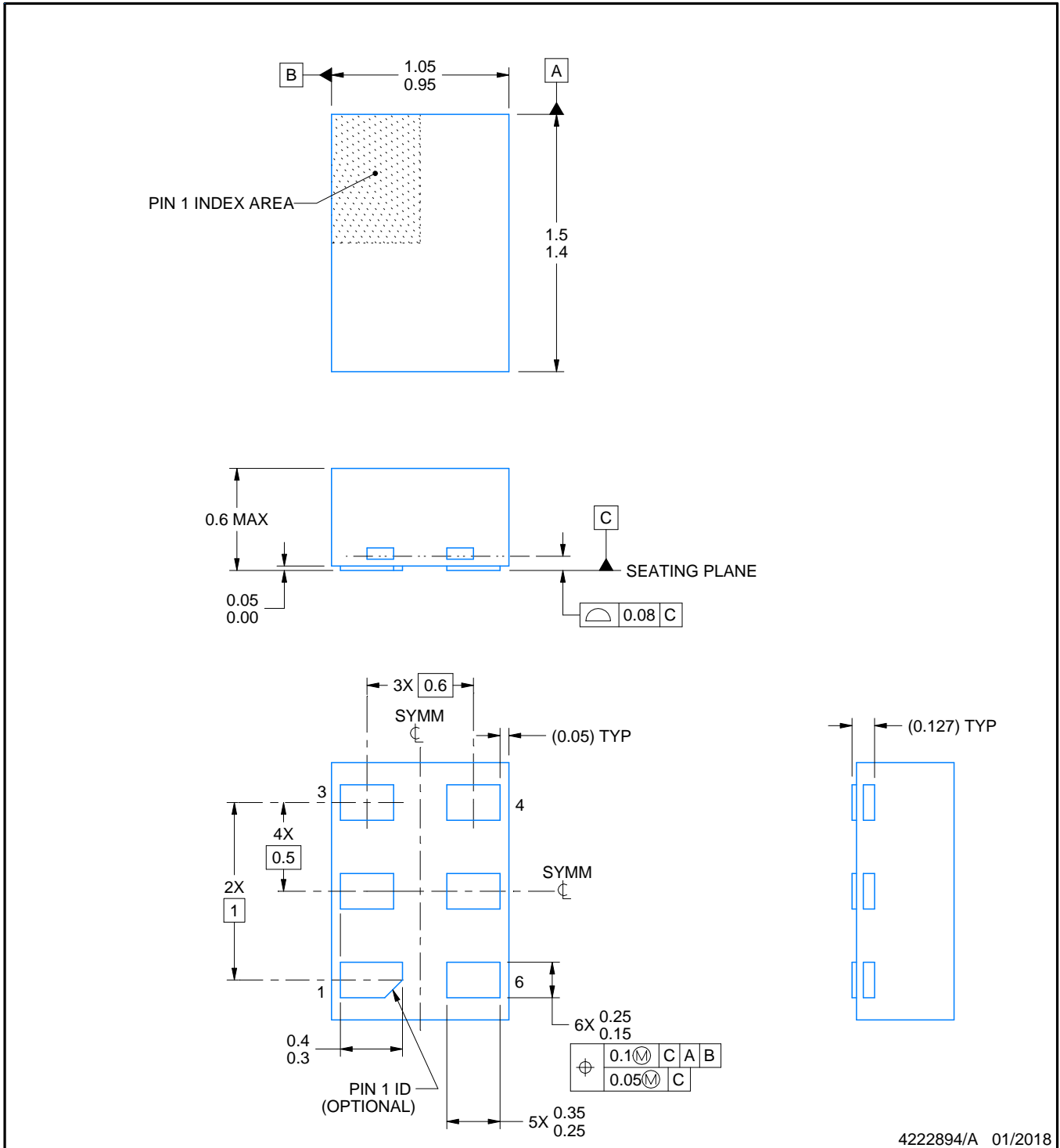
4222894/A   01/2018

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

SYMM

(0.35)

5X (0.3)

1

6

6X (0.2)

SYMM

4X (0.5)

3

4

(R0.05) TYP

(0.6)

LAND PATTERN EXAMPLE
1:1 RATIO WITH PKG SOLDER PADS
EXPOSED METAL SHOWN
SCALE:40X

0.05 MAX
ALL AROUND

EXPOSED
METAL

SOLDER MASK
OPENING

METAL

**NON SOLDER MASK
DEFINED**

0.05 MIN
ALL AROUND

EXPOSED
METAL

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

**SOLDER MASK
DEFINED
(PREFERRED)**

SOLDER MASK DETAILS

4222894/A   01/2018

NOTES: (continued)

3. For more information, see QFN/SON PCB application report in literature No. SLUA271 (www.ti.com/lit/slua271).

SYMM

(0.35)

5X (0.3)

1

6

6X (0.2)

SYMM

4X (0.5)

3

4

(R0.05) TYP

(0.6)
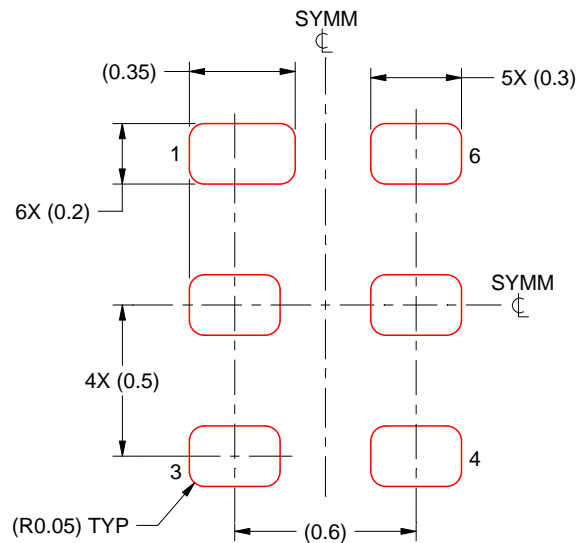
SOLDER PASTE EXAMPLE
BASED ON 0.075 - 0.1 mm THICK STENCIL
SCALE:40X

4222894/A   01/2018

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

B | 1.05 / 0.95 | A

1.05 / 0.95

PIN 1 INDEX AREA

0.4 MAX

C

SEATING PLANE

⌒ | 0.05 | C

(0.11) TYP

0.05 / 0.00

SYMM

3

4

SYMM

2X | 0.7

4X | 0.35

1

6

(0.1) PIN 1 ID

6X | 0.45 / 0.35

6X | 0.22 / 0.12

⊕ | 0.07 Ⓜ | C | B | A

0.05 Ⓜ | C

4220597/B   06/2022

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC registration MO-287, variation X2AAF.

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:40X

6X (0.6)

6X (0.17)

4X (0.35)

(0.8)

(R0.05) TYP

SYMM

SYMM

1

6

3

4

0.07 MAX
ALL AROUND

EXPOSED METAL

SOLDER MASK
OPENING

METAL

NON SOLDER MASK
DEFINED

0.07 MIN
ALL AROUND

EXPOSED METAL

METAL UNDER
SOLDER MASK
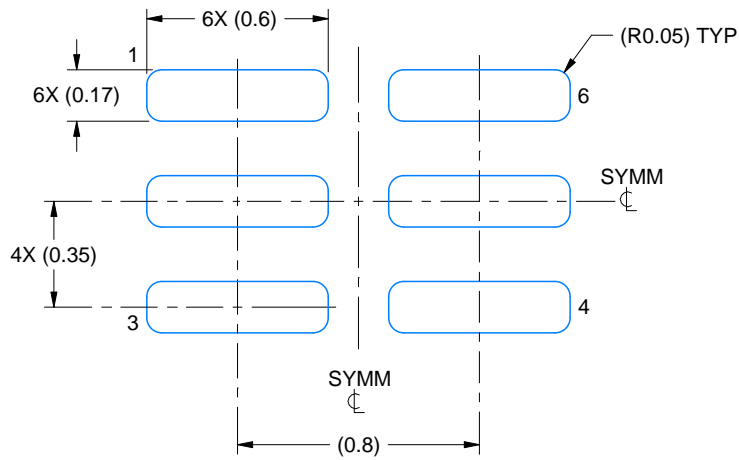
SOLDER MASK
OPENING

SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4220597/B   06/2022

NOTES: (continued)

4. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

6X (0.6)

1

6X (0.15)

6

(R0.05) TYP

SYMM
℄

4X (0.35)

3

4

SYMM
℄

(0.8)

SOLDER PASTE EXAMPLE
BASED ON 0.09 mm THICK STENCIL

PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:40X

4220597/B   06/2022

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.